

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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EOL announced Product

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SWITCHING

N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3634 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

FEATURES

- High voltage: $V_{DSS} = 200\text{ V}$
- Gate voltage rating: $\pm 30\text{ V}$
 $R_{DS(on)} = 0.60\ \Omega\ \text{MAX.}$ ($V_{GS} = 10\text{ V}$, $I_D = 3.0\text{ A}$)
- Low C_{iss} : $C_{iss} = 270\text{ pF TYP.}$ ($V_{DS} = 10\text{ V}$, $V_{GS} = 0\text{ V}$)
- Built-in gate protection diode
- TO-251/TO-252 package
- Avalanche capability rated

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0\text{ V}$)	V_{DSS}	200	V
Gate to Source Voltage ($V_{DS} = 0\text{ V}$)	V_{GSS}	± 30	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 6.0	A
Drain Current (Pulse) ^{Note1}	$I_{D(pulse)}$	± 18	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	20	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Single Avalanche Current ^{Note2}	I_{AS}	6.0	A
Single Avalanche Energy ^{Note2}	E_{AS}	3.6	mJ
Repetitive Avalanche Current ^{Note3}	I_{AR}	6.0	A
Repetitive Pulse Avalanche Energy ^{Note3}	E_{AR}	2.0	mJ

Notes 1. $PW \leq 10\ \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 100\text{ V}$, $R_G = 25\ \Omega$, $V_{GS} = 20 \rightarrow 0\text{ V}$, $L = 100\ \mu\text{H}$

3. $T_{ch} \leq 125^\circ\text{C}$, $R_G = 25\ \Omega$, $V_{DD} = 100\text{ V}$

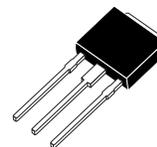
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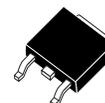
ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3634	TO-251 (MP-3)
2SK3634-Z	TO-252 (MP-3Z)

(TO-251)



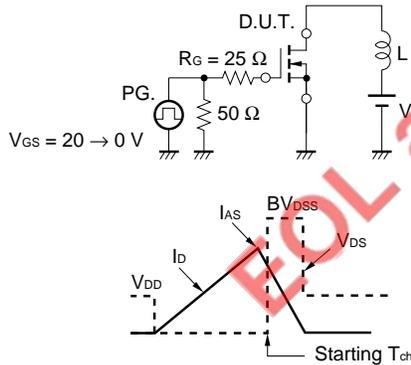
(TO-252)



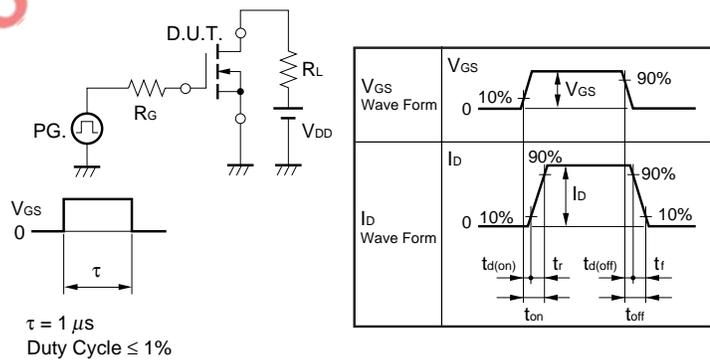
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 200 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5	3.5	4.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 3.0 A	2	4		S
Drain to Source On-state Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 3.0 A		0.47	0.60	Ω
Input Capacitance	C _{iss}	V _{DS} = 10 V		270		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		75		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		33		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 100 V, I _D = 3.0 A		4		ns
Rise Time	t _r	V _{GS} = 10 V		8		ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		14		ns
Fall Time	t _f			6		ns
Total Gate Charge	Q _G	V _{DD} = 160 V		9		nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V		1.5		nC
Gate to Drain Charge	Q _{GD}	I _D = 6.0 A		4.5		nC
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 16 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	t _{rr}	I _F = 6 A, V _{GS} = 0 V		100		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		320		nC

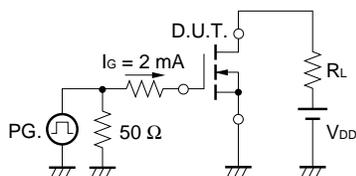
TEST CIRCUIT 1 AVALANCHE CAPABILITY



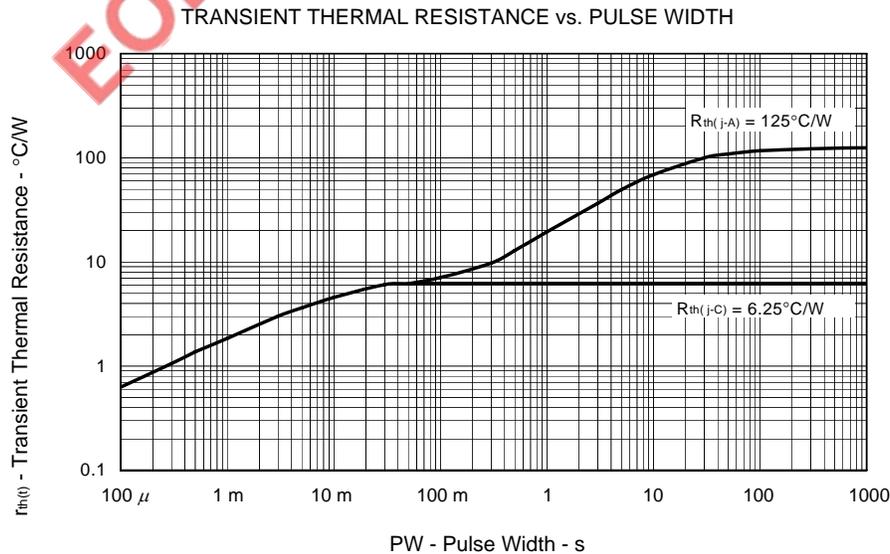
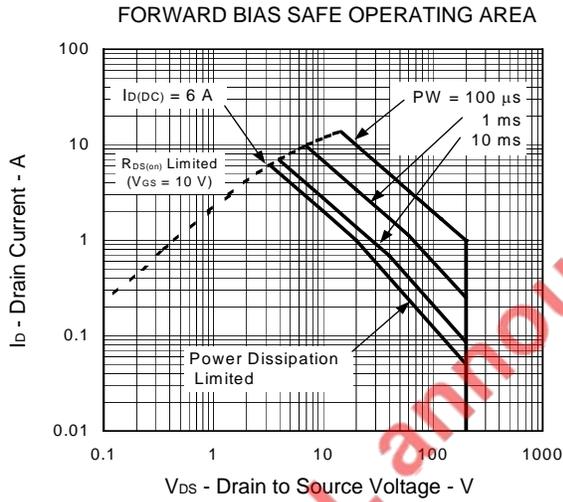
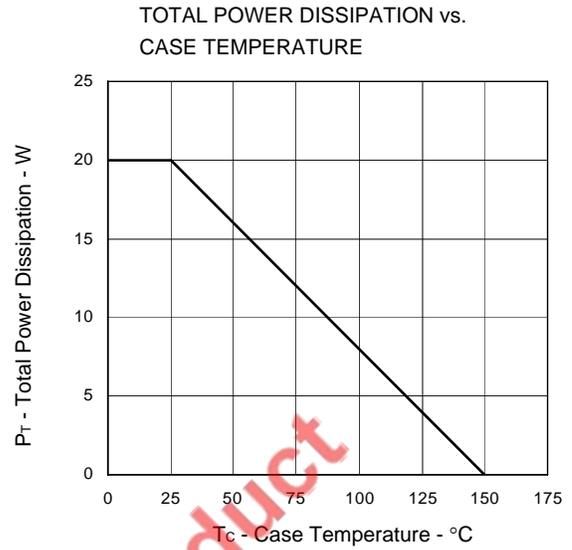
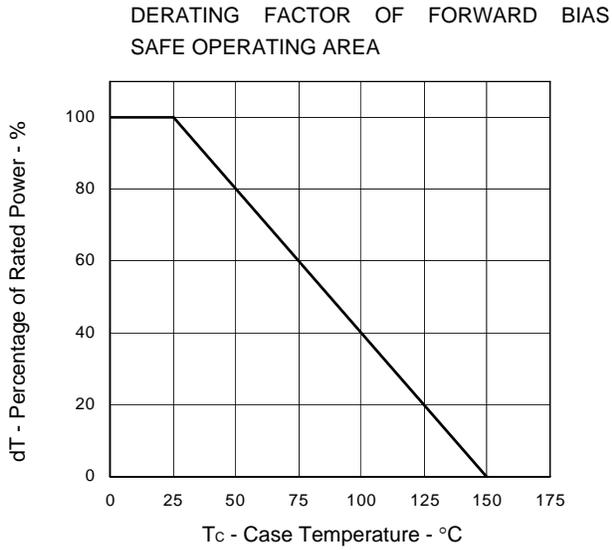
TEST CIRCUIT 2 SWITCHING TIME



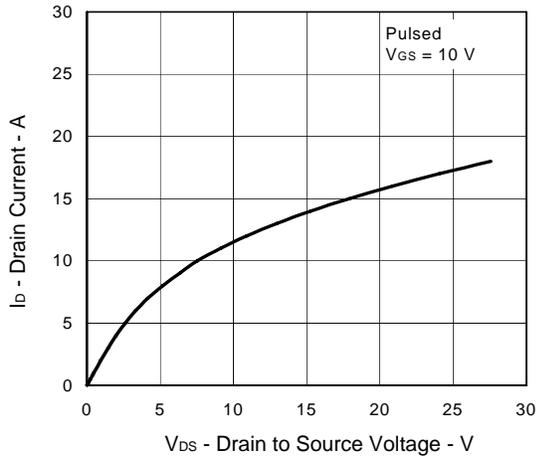
TEST CIRCUIT 3 GATE CHARGE



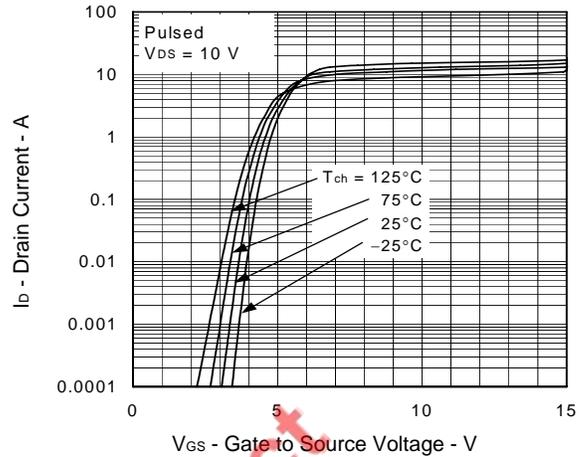
TYPICAL CHARACTERISTICS (T_A = 25°C)



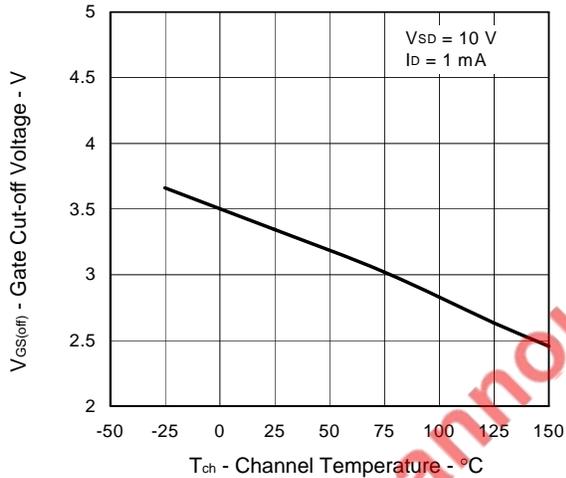
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



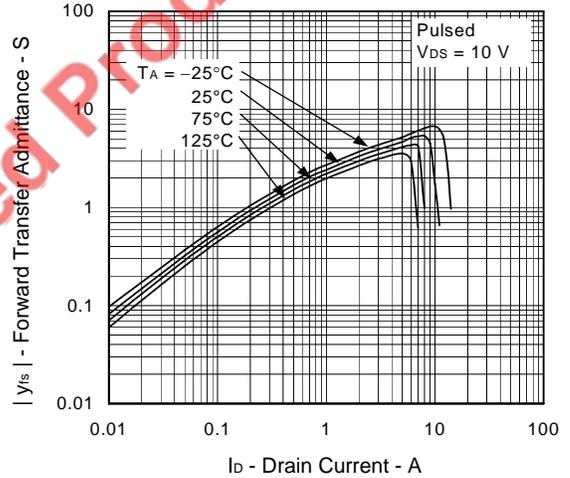
FORWARD TRANSFER CHARACTERISTICS



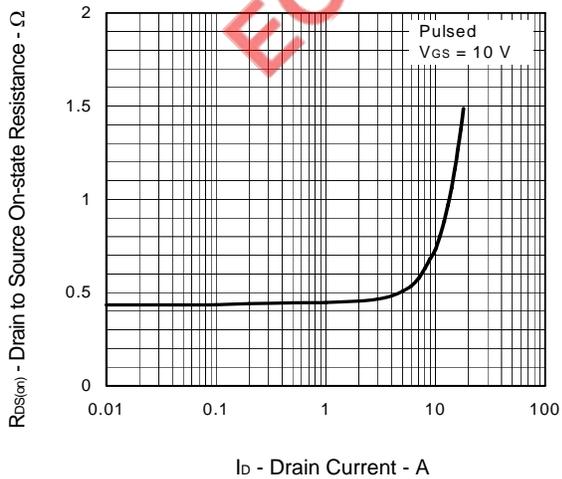
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



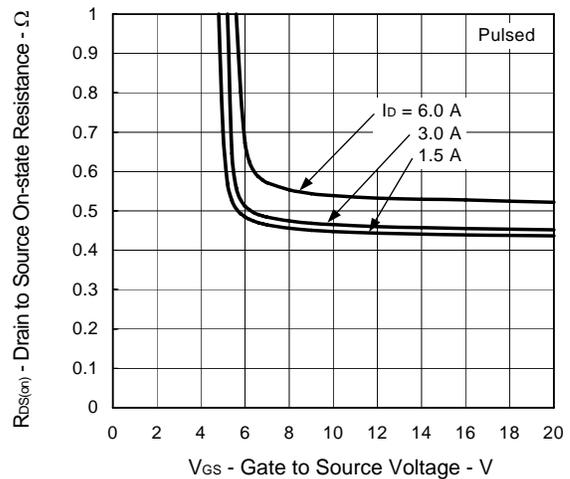
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



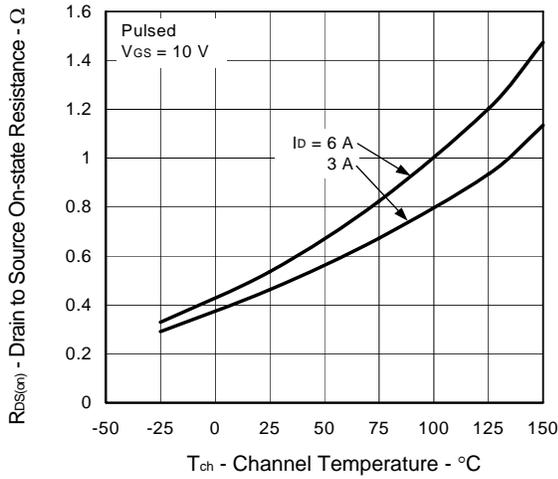
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



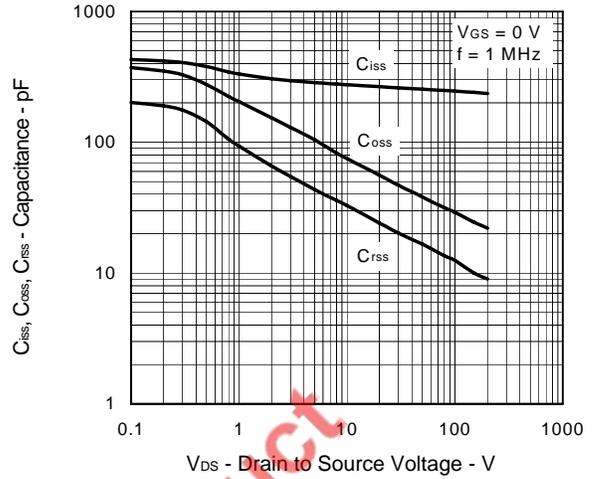
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



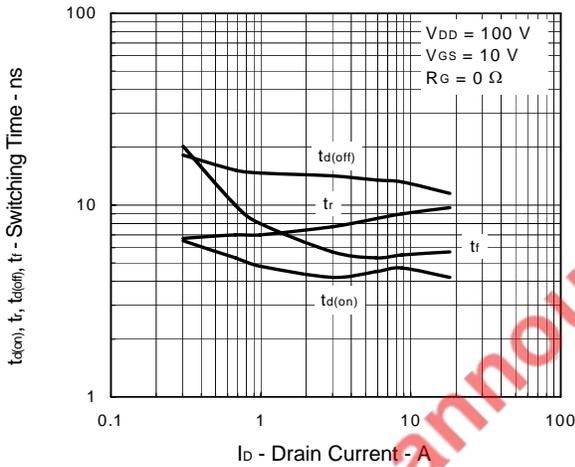
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



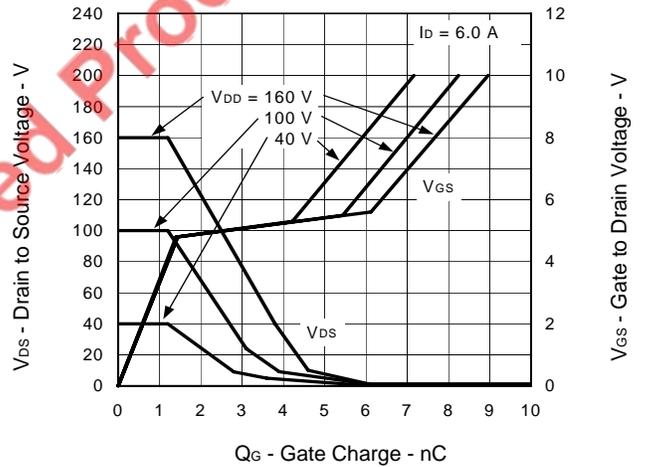
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



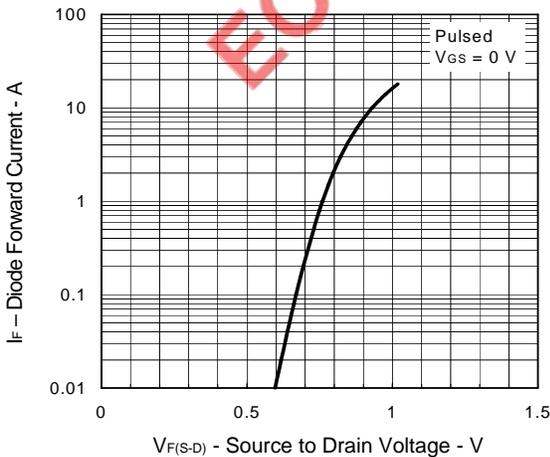
SWITCHING CHARACTERISTICS



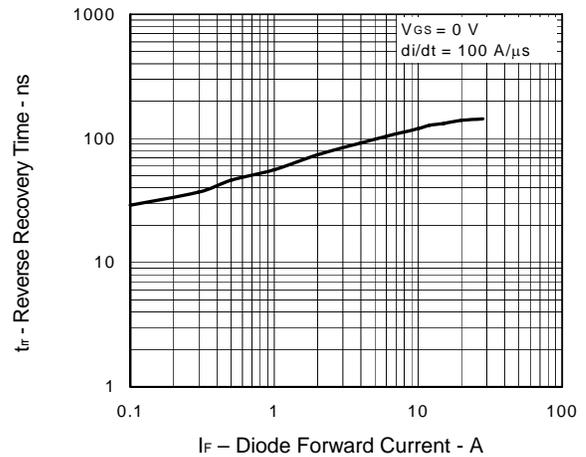
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



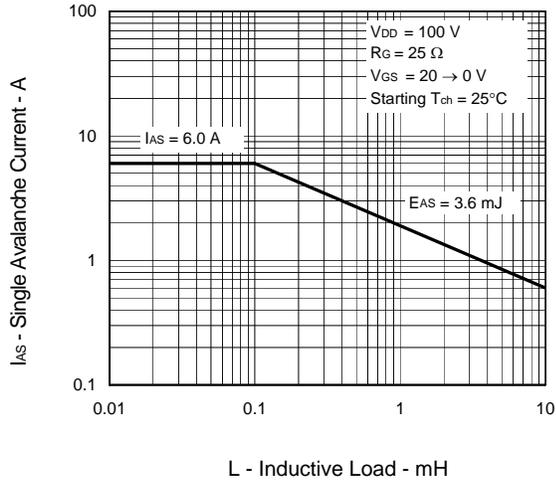
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



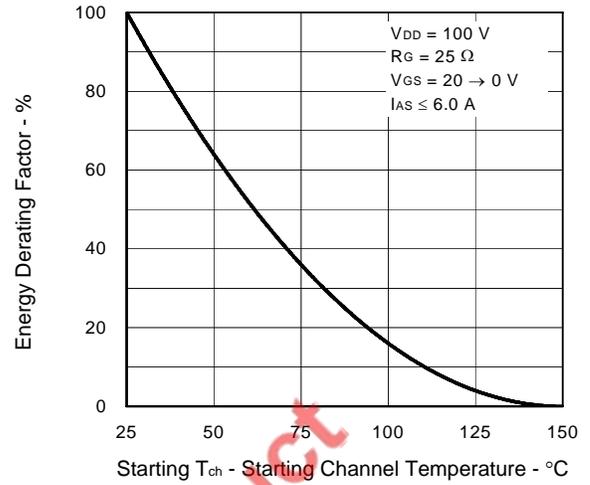
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



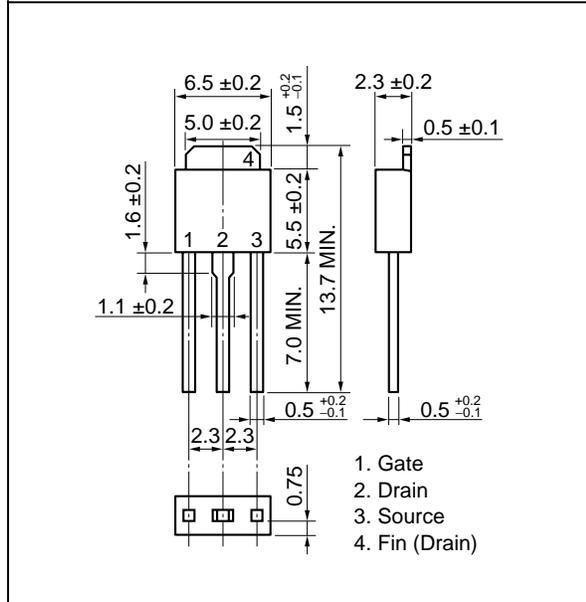
SINGLE AVALANCHE ENERGY DERATING FACTOR



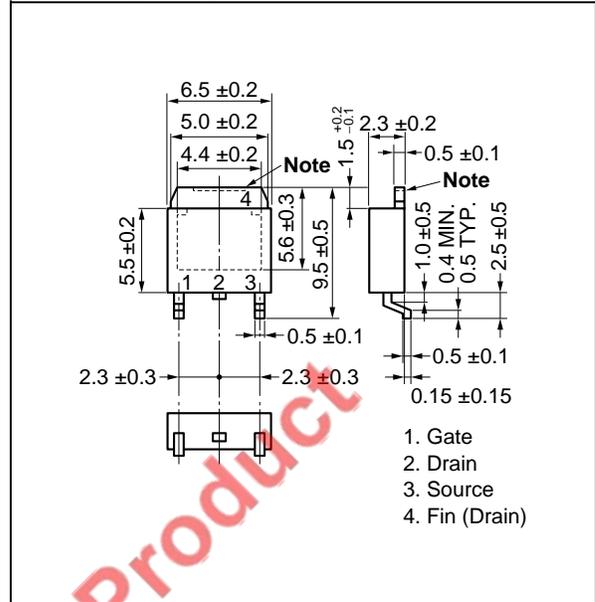
EOL announced Product

PACKAGE DRAWINGS (Unit: mm)

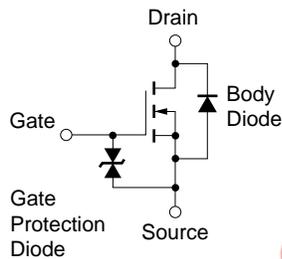
1) TO-251 (MP-3)



<R> 2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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